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## Theory of Half-metallic Ferrimagnetism in Double Perovskites

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Double perovskites like  $Sr_2FeMoO_6$  are rare examples of materials with half-metallic ground states and a ferrimagnetic  $T_c$  above room temperature. We present a comprehensive theory of the temperature and disorder dependence of their magnetic properties by deriving and validating a new effective spin Hamiltonian for these materials, amenable to large-scale three-dimensional simulations. We show how disorder, ubiquitous in these materials, affects  $T_c$ , the magnetization, and the conduction electron polarization. We conclude with a novel proposal to enhance  $T_c$  without sacrificing polarization.

There are very few examples of materials that exhibit half-metallic ground states, with fully spin-polarized conduction electrons, together with a ferromagnetic  $T_c$  above room temperature. This combination of properties have the potential for enormous technological impact in spin-tronic applications like tunneling magnetoresistance devices. The two classes of materials that offer the most promise for room temperature applications are double perovskites and Heusler alloys, both of which have several examples with  $T_c$  well above room temperature.

The double perovskites (DPs) are of particular interest since the perovskite family shows an amazingly rich variety of properties including colossal magnetoresistance, multiferroic behavior, and high  $T_c$  superconductivity. In the long run, the ability to make heterostructures of such multifunctional oxides is likely to open up very interesting possibilities, provided the stoichiometry and ordering of these materials can be controlled.

One of the best studied half-metallic DPs is  $Sr_2FeMoO_6$  (SFMO) with  $T_c \simeq 420K$ , well above room temperature [1–3]. SFMO is but one example of a DP  $A_2BB'O_6$ , which is derived from the simple ABO<sub>3</sub> perovskite structure by a three-dimensional (3D) checker-board ordering of B and B' ions.

From a theoretical point of view, we argue that DPs are *simple* systems for understanding metallic ferromagnetism, despite their apparent complexity. First, in contrast to ferromagnets like iron, there is a clear separation of the localized (B) and itinerant degrees of freedom (coming from B') in the DPs. Second, in contrast to the manganites, DPs have neither Jahn-Teller distortions nor, given the large separation between B-sites, antiferromagnetic superexchange that competes with double-exchange. This, in fact, is the main reason for the higher  $T_c$ 's in the DPs compared with the manganites. Third, in contrast to dilute magnetic semiconductors, disorder is not an essential aspect of the theoretical problem.

Previous theoretical work on half-metallic DPs includes pioneering T=0 electronic structure calculations [2, 3] and model Hamiltonians analyzed using various mean-field theories [4–6] and two-dimensional (2D) simulations [7]. In this Letter, we present a comprehen-

sive theory that gives insight into the temperature and disorder dependence of the magnetic properties of half-metallic DPs. We make detailed comparisons with and predictions for SFMO.

Our main results are:

- (1) We show that both the total magnetization M(T) and the conduction electron polarization P(T) at  $E_f$  are proportional to the magnetization  $M_S(T)$  of localized Fe spins. This result is significant because, while M(T) is much simpler to measure than P(T), the latter is of crucial importance for spintronic applications.
- (2) Our main theoretical advance is the derivation and validation of an effective classical spin Hamiltonian  $H_{\text{eff}}$  [see eq. (2)] for DPs, which differs from both the Heisenberg and Anderson-Hasegawa models [8]. We show that  $H_{\text{eff}}$  describes the full T-dependence of the magnetization  $M_S(T)$ , and in turn that of M(T) and P(T).
- (3) We present the results of simulations of  $H_{\rm eff}$  on large 3D lattices, including disorder effects, thus going beyond all previous theoretical calculations on SFMO.
- (4) We compute M(T) and  $T_c$ , using microscopic bandstructure parameters as input, and see how these are affected by deviations from stoichiometry and by anti-site (AS) disorder, ubiquitous in real materials. Ours is the first theory to show that  $T_c$  is insensitive to AS disorder, in excellent agreement with experiments, even though M(0) is suppressed.
- (5) We conclude with a novel proposal to increase  $T_c$  of SFMO, which in turn enhances the polarization P(T) at high temperatures, by using a combination of excess-Fe disorder and La-doping to maintain carrier density.

**Model Hamiltonian:** For large Hund's coupling  $J_H$ , the Fe<sup>3+</sup> (3 $d^5$ ) site has a S=5/2 "core spin" or local moment. The Mo<sup>5+</sup> (4 $d^1$ ) contributes a t<sub>2g</sub> electron which hybridizes via O with the Fe t<sub>2g</sub> states. Symmetry implies that  $d_{\alpha\beta}$  electrons delocalize only in the ( $\alpha$ ,  $\beta$ )-plane [9]. Thus the motion of electrons in the 3D system decouples into three 2D planes. The "double exchange" Hamiltonian [5, 7] describing itinerant electrons interacting with core spins is:

$$H = -t \sum_{\langle i,j \rangle, \sigma} (\epsilon_{i\sigma} d^{\dagger}_{i\downarrow} c_{j\sigma} + h.c.)$$

$$-t' \sum_{\langle j,j'\rangle,\sigma} c_{j\sigma}^{\dagger} c_{j'\sigma} + \Delta \sum_{i} d_{i\downarrow}^{\dagger} d_{i\downarrow}$$
 (1)

Here  $d_{i\sigma}\left(c_{i\sigma}\right)$  are fermion operators on the Fe (Mo) sites with spin  $\sigma$ . At the Fe sites i, we choose local axes of quantization along  $\mathbf{S}_i$  and Pauli exclusion prohibits an  $\uparrow$  electron. For all the Mo sites j, we choose the same (global) axis of quantization. The orientation  $(\theta_i, \varphi_i)$  of the classical spins  $\mathbf{S}_i$  then affects the Mo-Fe hopping via  $\epsilon_{i\uparrow} = -\sin(\theta_i/2)\exp(i\varphi_i/2)$  and  $\epsilon_{i\downarrow} = \cos(\theta_i/2)\exp(-i\varphi_i/2)$ .

The parameters in H are the hopping amplitudes t, between nearest neighbor (Fe-Mo) sites, and t', between two Mo sites, and the charge transfer energy  $\Delta$  between Fe  $t_{2g\downarrow}$  and Mo  $t_{2g}$  states; see Fig. 1(a). For now, we choose t=1 as our unit of energy [10]. Symmetry dictates t'>0. We choose t'/t=0.1 and  $\Delta/t=2.5$ , using realistic band parameters for SFMO as input [3]. We will show below that t sets the scale for the magnetic  $T_c$ , and that choosing t=0.27 eV, consistent with ref. [3], leads to the experimental  $T_c=420$  K of SFMO.

We use exact diagonalization (ED) to solve the quantum mechanics of "fast" itinerant electrons moving in the background of "slow" S=5/2 spins, for which we use a  $T \neq 0$  classical Monte Carlo (MC) simulation. The separation of time scales is justified below. Using standard ED-MC techniques, supplemented by T=0 variational calculations, we obtain the results shown in Figs. 1 and 2. These results are limited to 2D systems because of the computational cost of ED. We will present below results on large 3D systems using a different technique.

We show in Fig. 1(b) the band structure and the spinresolved density of states (DOS)  $N_{\sigma}(E)$  for the ferrimagnetic ground state of SFMO with n=0.33 electrons per unit cell per plane. These results are consistent with photoemission experiments [11]. We find that the conduction electrons, with magnetization  $M_{el}(T=0)=1\mu_B$  (per unit cell), are polarized opposite to the Fe spins, with core spin magnetization  $M_S(0)=5\mu_B$ . The half-metallic ground state, with  $N_{\uparrow}(0)=0$  and  $N_{\downarrow}(0)\neq 0$ , has a net magnetization  $M(0)=M_S(0)-M_{el}(0)=4\mu_B$ .

We see from Fig. 2(a) that  $M_S(T)$ ,  $M_{el}(T)$ , and hence the total magnetization  $M(T) = M_S(T) - M_{el}(T)$ , all have essentially the same T-dependence. Another quantity of great interest is the conduction electron polarization P(T) at  $E_f$  which determines the tunneling magnetoresistance. This is defined by  $P(T) = [N_{\downarrow}(0) - N_{\uparrow}(0)]/[N_{\downarrow}(0) + N_{\uparrow}(0)]$ , with E = 0 in the DOS is measured from  $E_f$ . In Fig. 2(a), we also see that P(T) also follows the T-dependent  $M_S(T)$ .

Effective Spin Hamiltonian: The results of Fig. 2(a) imply that if we had a reliable theory for the core spin magnetization  $M_S(T)$ , we could understand all the magnetic properties of SFMO, including the polarization P(T). With this motivation, we derive an effective Hamiltonian  $H_{\text{eff}}$  for the core spins by generalizing the

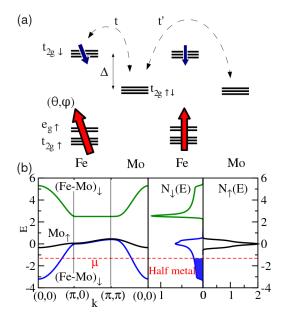


FIG. 1: (a) Schematic showing energy levels at transition metal sites in two unit cells (formula units) of SFMO. The Fe sites have localized S=5/2 core spins, treated as classical vectors with orientation  $(\theta,\varphi)$ . The parameters t,t' and  $\Delta$  of the Hamiltonian (1), governing the dynamics of the itinerant electrons in  $\mathbf{t}_{2g}$  orbitals, are also shown. (b) Calculated electronic structure  $E(\mathbf{k})$  and the spin-resolved DOS  $N_{\uparrow}(E)$  and  $N_{\downarrow}(E)$  in the ferrimagnetic ground state with all core spins up. Note the half-metallic ground state in SFMO with conduction electrons polarized opposite to core spins.

two-site Anderson-Hasegawa [8] analysis for manganites to double perovskites.

To derive  $H_{\text{eff}}$ , we find the exact solution of the full H of eq. (1) for one electron in two unit cells[12]. For a given  $\mathbf{t}_{2g}$  symmetry, the Hilbert space has three states per unit cell: Fe  $\mathbf{t}_{2g\downarrow}$  and Mo  $\mathbf{t}_{2g,\uparrow,\downarrow}$  leading to a  $6\times 6$  matrix for two unit cells. We analytically find its lowest eigenvalue as a function of the angle  $(\theta_i - \theta_j)$  between core spins. Working in two different geometries, we find [13] the nearest-neighbor  $(J_1)$  and next-nearest-neighbor  $(J_2)$  interaction energies; see inset in Fig. 2(b). Expressing these in terms of  $\mathbf{S}_i \cdot \mathbf{S}_j$ , where each  $\mathbf{S}_i$  is a unit vector, we obtain the effective Hamiltonian

$$H_{\text{eff}} = -J_1 \sum_{\langle i,j \rangle} F_1 \left( \mathbf{S}_i \cdot \mathbf{S}_j \right) - J_2 \sum_{\langle \langle i,j \rangle \rangle} F_2 \left( \mathbf{S}_i \cdot \mathbf{S}_j \right) \quad (2)$$

where the functions  $F_1(x) = 8\sqrt{2 + \sqrt{2 + 2x}}$  and  $F_2(x) = (5+\sqrt{5})\sqrt{6+2\sqrt{3+2x}}$ . Our two-unit cell analysis gives explicit expressions [13] for  $J_1$  and  $J_2$ , both of which are ferromagnetic with their scale set by the kinetic energy t of delocalization. We emphasize that the double square-root form of  $H_{\text{eff}}$  is quite different from the (single square-root) Anderson-Hasegawa model.

Next we need to understand how we can use  $H_{\text{eff}}$  going beyond the simple two-unit cell derivation. Specifically:

(i) How can we relate  $J_1$ ,  $J_2$  to  $t,t',\Delta$  and the filling n? (ii) To what extent does  $H_{\rm eff}$  capture the essential physics of the full Hamiltonian H?

The dependence of  $J_1$  and  $J_2$  on microscopic parameters can be obtained by matching the spin-wave (SW) spectra of  $H_{\rm eff}$  and H. This comparison is shown in Fig. 2(b) along certain symmetry directions. We find SW dispersion for H using ED to compute the energy of electrons moving in a "frozen" spin-wave background. The low energy scale of 0.1t for spin dynamics (see Fig. 2(b)) justifies a posteriori our assumption of "slow" spins and "fast" electrons, whose bandwidth is of order t (see Fig. 1(b)). The same separation of energy scales also justifies the use of T-independent exchange couplings  $J_1$  and  $J_2$  for all  $T < T_c$ , as we discuss next.

To validate the effective model  $H_{\rm eff}$ , we show in Fig. 2(c) that it reproduces the magnetization M(T) of the full Hamiltonian H over the entire range of temperatures. In contrast the Heisenberg model  $H_{\rm Heis}$  gives quite different results, except in the  $T\to 0$  limit with small spin deviations. Thus M(T) for the DP's cannot be described by a Heisenberg model, while  $H_{\rm eff}$  provides an excellent description of the ED-MC result .

The classical  $H_{\rm eff}$  can be easily simulated on large 3D lattices, unlike the full H, and the results are shown in Fig. 2(d). We note the linear drop in M(T) at low T, due to classical spin-waves, followed by a rapid suppression of M at the phase transition [14]. Our M(T) results are in qualitative agreement with recent experiments [15]. We estimate  $T_c$  in the infinite volume limit using finite size scaling of results obtained on  $L^3$  systems with L=8, 12 and 16; see Supplementary materials for details. For t'/t=0.1 and  $\Delta/t=2.5$ , we find  $T_c=0.14t$ . Comparing this to  $T_c=420$ K for pure SFMO, we obtain t=0.27 eV, consistent with ref. [3].

**Disorder:**  $H_{\rm eff}$  permits us to model various kinds of disorder and deviations from stoichiometry [13]. (i) Excess Fe is modeled with an extra spin (at a Mo site) that interacts with its neighboring spins with a large antiferromagnetic (AF) superexchange  $S(S+1)J_{\rm AF}\simeq 34$  mev [16]. (ii) Excess Mo is modeled by removing an Fe spin from the lattice. Both (i) and (ii) also require reevaluation of  $J_1$  and  $J_2$  due to change in carrier density n. (iii) Here we focus on anti-site (AS) disorder, the most common form of disorder in DPs, with Fe and Mo interchanged and no change in n.

We see from Fig. 3 that AS disorder systematically reduces M(0) without affecting  $T_c$ , in excellent agreement with experiments [17]. We quantify AS disorder using  $\delta$  the fraction of Fe atoms that are on the Mo sublattice. The observed magnetization  $M(0)[1-2\delta]$  arises from the loss of two moments for each AS defect. One from the moment lost at the Mo (on the Fe sublattice) and the other from the Fe (on the Mo sublattice) antiferromagnetically coupled to its neighbors via  $J_{\rm AF}$ .

There are two opposite effects of AS disorder on  $T_c$  that

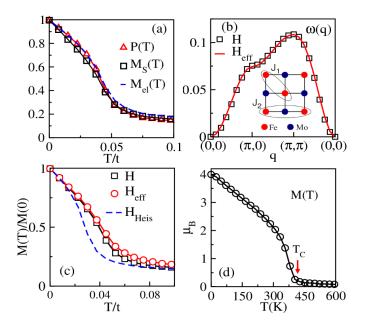


FIG. 2: (a) The core spin magnetization  $M_S(T)$ , conduction electron magnetization  $M_{el}(T)$  and polarization P(T) at  $E_f$  calculated using ED-MC method. Both  $M_S(T)$  and  $M_{el}(T)$  are normalized to their  $T{=}0$  values. We conclude that all magnetic properties are proportional to  $M_S(T)$ . (b) Spin wave dispersion of full Hamiltonian H, obtained by exact diagonalization, compared with that of the effective Hamiltonian  $H_{\rm eff}$ . Inset: Fe-Mo lattice showing nearest-neighbor  $(J_1)$  and next-nearest-neighbor  $(J_2)$  interactions of  $H_{\rm eff}$ . (c) The normalized magnetization M(T) for three Hamiltonians: H,  $H_{\rm eff}$  and the Heisenberg model. These results are obtained on  $8^2$  systems with error bars no larger than the symbol size. (d) Magnetization M(T) from 3D simulations of  $H_{\rm eff}$  on  $16^3$  systems. The infinite system  $T_c$  is obtained from finite size scaling (see Supplementary materials).

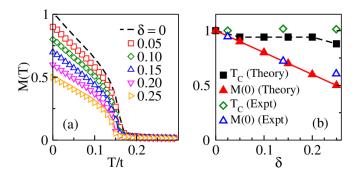


FIG. 3: (a) M(T), normalized by the M(0) for the disorder-free system, for various values of anti-site (AS) disorder  $\delta$  (see text). (b) Theoretical results for  $T_c$  and  $T{=}0$  magnetization M(0) (both normalized with respect to their disorder-free values) compared with experiments [17]. M(0) drops like  $2\delta$ , while  $T_c$  is insensitive to AS disorder.

appear to balance each other. The strong Fe-Fe superexchange  $J_{\rm AF}$  pins the spins surrounding the Fe-defect, and makes the magnetic order more robust against thermal

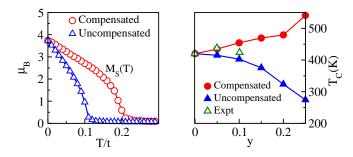


FIG. 4: (a) Core spin magnetization  $M_S(T)$  for  $\text{La}_x \text{Sr}_{2-x} \text{Fe}_{1+y} \text{Mo}_{1-y} \text{O}_6$  for uncompensated (x,y) = (0,0.25) and compensated (x,y) = (0.75,0.25) Fe-rich systems. (b) The uncompensated  $T_c(y)$  is compared with experiments [21]. Our prediction for compensated (x=3y) system shows large enhancement in  $T_C$ .

fluctuations. On the other hand, the Mo-defect leads to broken  $J_1, J_2$  bonds which weaken the magnetism. The net effect is a  $T_c$  insensitive to  $\delta$  for moderate levels of AS disorder, which is exactly what experiments observe. We note that while the loss of M(0) with AS disorder has been explained earlier [18–20], ours is the first theory to correctly account for  $T_c(\delta)$ ; previous theories either found a drop [18] in  $T_c$  or an increase [5].

**Raising**  $T_c$ : We conclude with a proposal to raise the ferrimagnetic  $T_c$  without sacrificing the conduction electron polarization P; see Fig. 4. In brief, it involves adding excess Fe and compensating for the loss of mobile carriers by La substitution on the Sr site.

To see how this works, let us first consider excess Fe without any compensation:  $\operatorname{Sr}_2\operatorname{Fe}_{1+y}\operatorname{Mo}_{1-y}\operatorname{O}_6$ . In this case,  $M_S(0)$  decreases like y due to the AF alignment of excess spins.  $T_c$  also decreases with y because the loss of carriers n=(1-3y)/3 dominates over the enhanced pinning of moments by  $J_{\mathrm{AF}}$  in the vicinity of defects . For the uncompensated case, the calculated  $T_c(y)$  in Fig. 4(b) is in reasonable agreement with experiments [21].

We can compensate for the carriers by A-site substitution:  $\text{La}_x \text{Sr}_{2-x} \text{Fe}_{1+y} \text{Mo}_{1-y} \text{O}_6$  with electron density n = (1+x-3y)/3 per plane. Choosing x = 3y counters the doping-dependent drop in  $T_c$  that dominated above and we find that  $T_c$  can be significantly enhanced over that of pure SFMO due to just the local pinning of moments at excess Fe sites. This increase in  $T_c$  goes handin-hand with an unchanged  $M_S(0)$ ; see Fig. 4(a).

We also note that the polarization P(0) remains 100%. When the Fe spins cant at finite T, electrons depolarize by mixing of up and down states, however, no such processes are permitted at T=0, even in a disordered Ferich system. We have checked using the full Hamiltonian (1) that, even though the strict proportionality between  $M_S(T)$  and P(T) is not observed in the presence of disorder, the high temperature P is still enhanced over the

clean system due to the large increase in  $T_c$ .

An alternative way to enhance  $T_c$  is to add mobile electrons using La doping, which, however, has been shown to lead to considerable increase in AS disorder [22]. In principle, compensated doping as proposed here should introduce less AS disorder; see Supplementary materials.

In conclusion, while we have focused here on SFMO, our theory provides a general framework for understanding half metallic ferrimagnetism in DPs. Interesting directions for future work include A-site substitution, Coulomb correlations on B', which may become increasingly important for larger carrier concentrations, and spin-orbit coupling on B' for 5d elements.

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